

1.本站收集的数据手册和产品资料都来自互联网,版权归原作者所有。如读者和版权方有任 何异议请及时告之,我们将妥善解决。

本站提供的中文数据手册是英文数据手册的中文翻译,其目的是协助用户阅读,该译文无法自动跟随原稿更新,同时也可能存在翻译上的不当。建议读者以英文原稿为参考以便获得更精准的信息。

3.本站提供的产品资料,来自厂商的技术支持或者使用者的心得体会等,其内容可能存在描 叙上的差异,建议读者做出适当判断。

4.如需与我们联系,请发邮件到marketing@iczoom.com,主题请标有"数据手册"字样。

Read Statement

1. The datasheets and other product information on the site are all from network reference or other public materials, and the copyright belongs to the original author and original published source. If readers and copyright owners have any objections, please contact us and we will deal with it in a timely manner.

2. The Chinese datasheets provided on the website is a Chinese translation of the English datasheets. Its purpose is for reader's learning exchange only and do not involve commercial purposes. The translation cannot be automatically updated with the original manuscript, and there may also be improper translations. Readers are advised to use the English manuscript as a reference for more accurate information.

3. All product information provided on the website refer to solutions from manufacturers' technical support or users the contents may have differences in description, and readers are advised to take the original article as the standard.

4. If you have any questions, please contact us at marketing@iczoom.com and mark the subject with "Datasheets".

874003DI-02

PRODUCT DISCONTINUATION NOTICE - LAST TIME BUY EXPIRES SEPTEMBER 7, 2016

DATA SHEET

GENERAL DESCRIPTION

The 874003DI-02 is a high performance Dif-ferential-to-LVDS Jitter Attenuator designed for use in PCI Express[™] systems. In some PCI Express systems, such as those found in desktop PCs, the PCI Express clocks are generated from a low bandwidth, high phase noise PLL frequency synthesizer. In these systems, a jitter attenuator may be required to attenuate high frequency random and deterministic jitter components from the PLL synthesizer and from the system board. The 874003DI-02 has a bandwidth of 3MHz. The 3MHz provides an intermediate bandwidth that can easily track triangular spread profiles, while providing good jitter attenuation.

The 874003DI-02 uses IDT's 3rd Generation FemtoClock[™] PLL technology to achieve the lowest possible phase noise. The device is packaged in a 20 Lead TSSOP package, making it ideal for use in space constrained applications such as PCI Express add-in cards.

- Three differential LVDS output pairs
- One differential clock input
- CLK and nCLK supports the following input types: LVPECL, LVDS, LVHSTL, SSTL, HCSL
- Output frequency range: 98MHz 320MHz
- Input frequency range: 98MHz 128MHz
- VCO range: 490MHz 640MHz
- Cycle-to-cycle jitter: 30ps (maximum)
- Supports PCI-Express Spread-Spectrum Clocking
- 3MHz PLL loop bandwidth
- 3.3V operating supply
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

FEATURES

F_SEL[2:0] FUNCTION TABLE

	Inputs		Outputs			
F_SEL2	F_SEL1	F_SEL0	QA0, nQA0:QA1, nQA1	QB0, nQB0		
0	0	0	÷2 (default)	÷2 (default)		
1	0	0	÷5	÷2		
0	1	0	÷4	÷2		
1	1	0	÷2	÷4		
0	0	1	÷2	÷5		
1	0	1	÷5	÷4		
0	1	1	÷4	÷5		
1	1	1	÷4	÷4		

BLOCK DIAGRAM

PIN ASSIGNMENT

$\begin{array}{c c} QA1 & \hline 1 \\ V_{DDO} & 2 \\ QA0 & 3 \\ nQA0 & 4 \\ MR & 5 \\ F_SEL0 & 6 \\ nc & 7 \\ V_{DDA} & 8 \\ F_SEL1 & 9 \end{array}$	20 nQA1 19 V _{DDO} 18 QB0 17 nQB0 16 F_SEL2 15 OEB 14 GND 13 nCLK 12 CLK						
V _{DD} 🗖 10	11 🗖 OEA						
874003DI-02 20-Lead TSSOP							
	mm x 0.92mm age body						

6.5mm x 4.4mm x 0.92mm package body **G Package** Top View

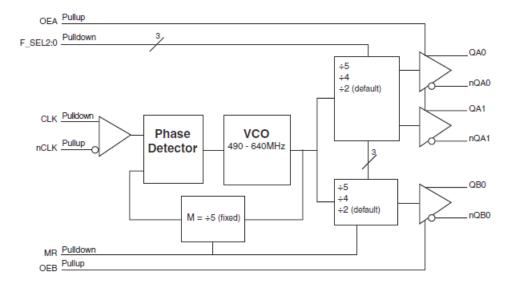


TABLE 1. PIN DESCRIPTIONS

Number	Name	Ту	уре	Description
1, 20	QA1, nQA1	Output		Differential output pair. LVDS interface levels.
2, 19	V	Power		Output supply pins.
3, 4	QA0, nQA0	Output		Differential output pair. LVDS interface levels.
5	MR	Input	Pulldown	Active HIGH Master Reset. When logic HIGH, the internal dividers are reset causing the true outputs (Qx) to go low and the inverted outputs (nQx) to go high. When logic LOW, the internal dividers and the outputs are enabled. LVCMOS/LVTTL interface levels.
6, 9, 16	F_SEL0, F_SEL1, F_SEL2	Input	Pulldown	Frequency select pin for QAx/nQAx and QB0/nQB0 outputs. LVCMOS/LVTTL interface levels.
7	nc	Unused		No connect.
8	V _{DDA}	Power		Analog supply pin.
10	V	Power		Core supply pin.
11	OEA	Input	Pullup	Output enable pin for QA pins. When HIGH, the QAx/nQAx outputs are active. When LOW, the QAx/nQAx outputs are in a high impedance state. LVCMOS/LVTTL interface levels.
12	CLK	Input	Pulldown	Non-inverting differential clock input.
13	nCLK	Input	Pullup	Inverting differential clock input.
14	GND	Power		Power supply ground.
15	OEB	Input	Pullup	Output enable pin for QB0 pins. When HIGH, the QB0/nQB0 outputs are active. When LOW, the QB0/nQB0 outputs are in a high impedance state. LVCMOS/LVTTL interface levels.
17, 18	nQB0, QB0	Output		Differential output pair. LVDS interface levels.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

TABLE 2. PIN CHARACTERISTICS

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C	Input Capacitance			4		pF
R	Input Pullup Resistor			51		kΩ
	Input Pulldown Resistor			51		kΩ

TABLE 3A. OEA OUTPUT ENABLE FUNCTION TABLE

Inputs	Outputs		
OEA	QA0/nQA0, QA1/nQA1		
0	High Impedance		
1	Enabled		

TABLE 3B. OEB OUTPUT ENABLE FUNCTION TABLE

Inputs	Outputs
OEB	QB0/nQB0
0	High Impedance
1	Enabled

Absolute Maximum Ratings

Supply Voltage, V_{dD}	4.6V
Inputs, V	-0.5V to V_{_{DD}}+ 0.5 V
Outputs, V_{o}	-0.5V to $V_{_{DDO}}$ + 0.5V
Package Thermal Impedance, $\boldsymbol{\theta}_{_{\!$	73.2°C/W (0 lfpm)
Storage Temperature, $T_{_{STG}}$	-65°C to 150°C

NOTE: Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics* or *AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Table 4A. Power Supply DC Characteristics, $V_{_{DD}} = V_{_{DDO}} = 3.3V \pm 5\%$, Ta = -40°C to 85°C

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V	Core Supply Voltage		3.135	3.3	3.465	V
	Analog Supply Voltage		V _{DD} – 0.15	3.3	V _{DD}	V
V	Output Supply Voltage		3.135	3.3	3.465	V
I DD	Power Supply Current				80	mA
	Analog Supply Current				15	mA
	Output Supply Current				75	mA

TABLE 4B. LVCMOS/LVTTL DC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, TA = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
V	Input High Voltage			2		V _{DD} + 0.3	V
V	Input Low Voltage			-0.3		0.8	V
		OEA, OEB	$V_{DD} = V_{N} = 3.465V$			5	μA
I _{IH}	Input High Current	F_SEL0, F_SEL1 F_SEL2, MR	$V_{_{DD}} = V_{_{IN}} = 3.465V$			150	μA
		OEA, OEB	$V_{DD} = 3.465 V, V_{IN} = 0 V$	-150			μA
I	Input Low Current	F_SEL0, F_SEL1 F_SEL2, MR	$V_{_{DD}} = 3.465 V, V_{_{IN}} = 0 V$	-5			μA

Table 4C. Differential DC Characteristics, $V_{dd} = V_{ddd} = 3.3V \pm 5\%$, Ta = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
	Input High Current	CLK	$V_{DD} = V_{N} = 3.465V$			150	μA
и		nCLK	$V_{DD} = V_{N} = 3.465V$	5			μA
	Input Low Current	CLK	$V_{DD} = V_{N} = 3.465V$			150	μA
1.L		nCLK	$V_{DD} = V_{N} = 3.465V$	-150			μA
V _{PP}	Peak-to-Peak Input Voltage; NOTE 1			0.15		1.3	V
V _{CMR}	Common Mode Inpu	ut Voltage; NOTE 1, 2		GND + 0.5		V _{DD} - 0.85	V

NOTE 1: V_{μ} should not be less than -0.3V.

NOTE 2: Common mode voltage is defined as V_{μ} .

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V _{od}	Differential Output Voltage		275	375	485	mV
$\Delta V_{_{OD}}$	$V_{_{OD}}$ Magnitude Change				50	mV
V _{os}	Offset Voltage		1.2	1.35	1.5	V
ΔV_{os}	V _{os} Magnitude Change				50	mV

TABLE 4D. LVDS DC CHARACTERISTICS, $V_{DD} = V_{DDO} = 3.3V \pm 5\%$, TA = -40°C to 85°C

Table 5. AC Characteristics, $V_{_{DD}} = V_{_{DDO}} = 3.3V \pm 5\%$, TA = -40°C to 85°C

Symbol	Parameter		Test Conditions	Minimum	Typical	Maximum	Units
f	Output Frequency			98		320	MHz
<i>t</i> jit(cc)	Cycle-to-Cycle Jitter, NOTE 1, 3					30	ps
<i>t</i> sk(o)	Output Skew; NOTE 2					185	ps
<i>t</i> sk(b)	Bank Skew; NOTE 1, 4	Bank A				65	ps
t _R / t _F	Output Rise/Fall Time		20% to 80%	250		700	ps
odc	Output Duty Cycle			47		53	%

 T_{A} , Ambient Temperature applied using forced air flow.

NOTE 1: This parameter is defined in accordance with JEDEC Standard 65.

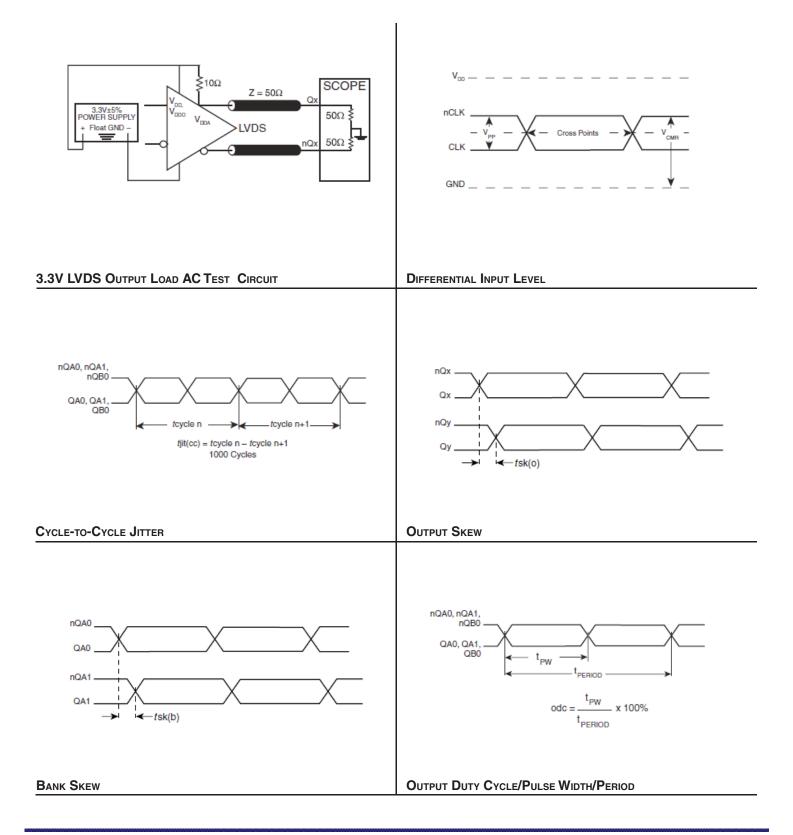
NOTE 2: These parameters are guaranteed by characterization. Not tested in production.

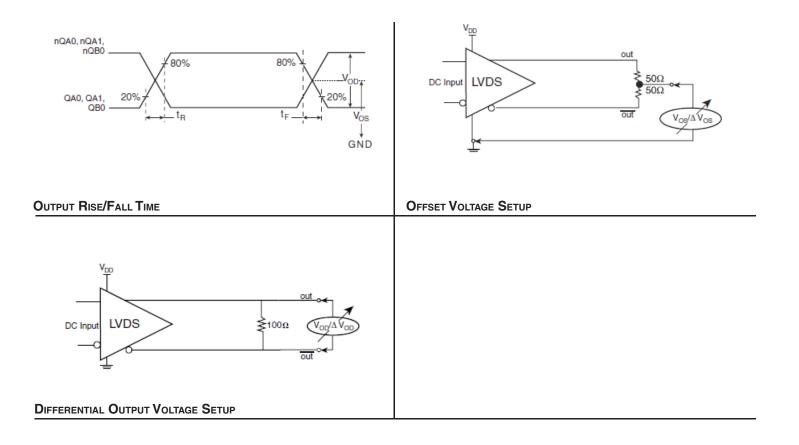
NOTE 3: Defined as skew between outputs at the same supply voltage and with equal load conditions.

Measured at the differential cross points.

NOTE 4: Defined as skew within a bank of outputs at the same voltages and with equal load conditions.

PARAMETER MEASUREMENT INFORMATION





APPLICATION INFORMATION

Power Supply Filtering Techniques

As in any high speed analog circuitry, the power supply pins are vulnerable to random noise. To achieve optimum jitter performance, power supply isolation is required. The 874003DI-02 provides separate power supplies to isolate any high switching noise from the outputs to the internal PLL. V_{DD}, V_{DDA}, and V_{DDD} should be individually connected to the power supply plane through vias, and 0.01µF bypass capacitors should be used for each pin. *Figure 1* illustrates this for a generic V_{DD} pin and also shows that V_{DDA} requires that an additional10Ω resistor along with a 10µF bypass capacitor be connected to the V_{DDA} pin.

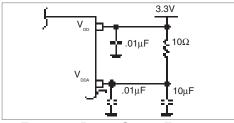


FIGURE 1. POWER SUPPLY FILTERING

WIRING THE DIFFERENTIAL INPUT TO ACCEPT SINGLE ENDED LEVELS

Figure 2 shows how the differential input can be wired to accept single ended levels. The reference voltage V_REF = $V_{D2}/2$ is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio

of R1 and R2 might need to be adjusted to position the V_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and $V_{_{DD}}$ = 3.3V, V_REF should be 1.25V and R2/ R1 = 0.609.

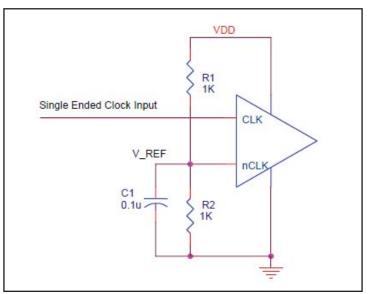


FIGURE 2. SINGLE ENDED SIGNAL DRIVING DIFFERENTIAL INPUT

DIFFERENTIAL CLOCK INPUT INTERFACE

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both signals must meet the V_{PP} and V_{CMR} input requirements. *Figures 3A to 3F* show interface examples for the CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please

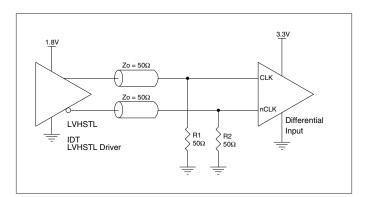


FIGURE 3A. CLK/nCLK INPUT DRIVEN BY AN IDT OPEN EMITTER LVHSTL DRIVER

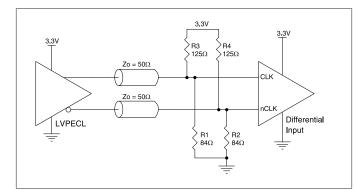


FIGURE 3C. CLK/nCLK INPUT DRIVEN BY A 3.3V LVPECL DRIVER

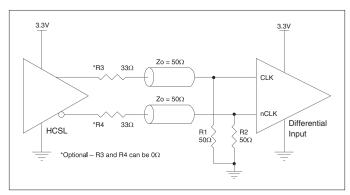


FIGURE 3E. CLK/nCLK INPUT DRIVEN BY A 3.3V HCSL DRIVER

consult with the vendor of the driver component to confirm the driver termination requirements. For example in Figure 3A, the input termination applies for IDT open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

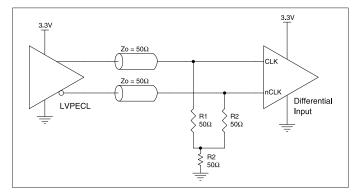


FIGURE 3B. CLK/nCLK INPUT DRIVEN BY A 3.3V LVPECL DRIVER

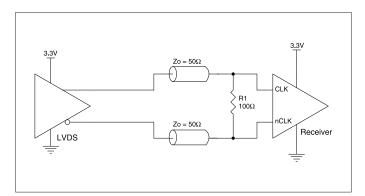


FIGURE 3D. CLK/nCLK INPUT DRIVEN BY A 3.3V LVDS DRIVER

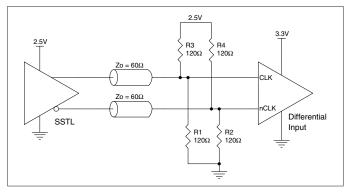


FIGURE 3F. CLK/nCLK INPUT DRIVEN BY A 2.5V SSTL DRIVER

RECOMMENDATIONS FOR UNUSED INPUT AND OUTPUT PINS

INPUTS: LVCMOS CONTROL PINS

All control pins have internal pull-ups or pull-downs; additional resistance is not required but can be added for additional protection. A $1k\Omega$ resistor can be used.

OUTPUTS: LVDS OUTPUTS

All unused LVDS output pairs can be either left floating or terminated with 100Ω across. If they are left floating, we recommend that there is no trace attached.

LVDS DRIVER TERMINATION

A general LVDS inteface is shown in *Figure 4*. In a 100Ω differential transmission line environment, LVDS drivers require a matched load termination of 100Ω across near the receiver

input. For a multiple LVDS outputs buffer, if only partial outputs are used, it is recommended to terminate the unused outputs.

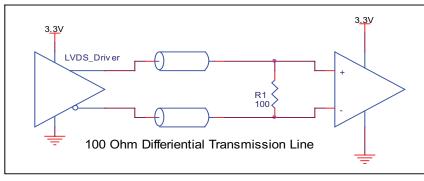


FIGURE 4. TYPICAL LVDS DRIVER TERMINATION

SCHEMATIC EXAMPLE

Figure 5 shows an example of 874003DI-02 application schematic. In this example, the device is operated at $V_{_{DD}} = V_{_{DDO}} = 3.3V$. The decoupling capacitors should be located as close as possible to the power pin. The input is driven by a 3.3V LVPECL driver. Two examples of LVDS terminations are shown in this schematic.

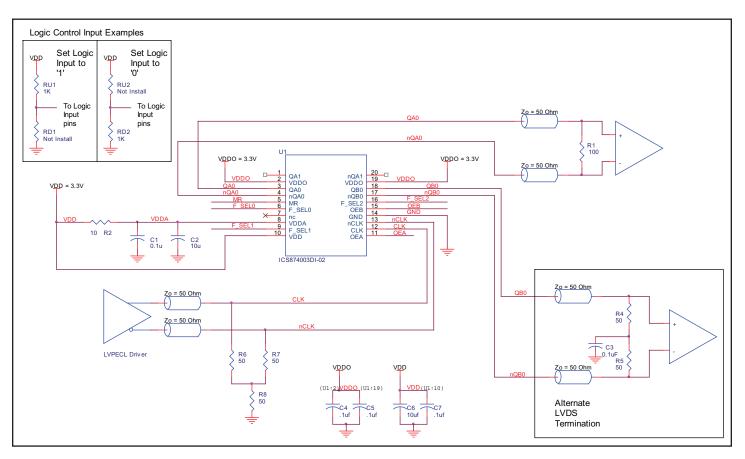


FIGURE 5. 874003DI-02 SCHEMATIC EXAMPLE

Power Considerations

This section provides information on power dissipation and junction temperature for the 874003DI-02. Equations and example calculations are also provided.

1. Power Dissipation.

The total power dissipation for the 874003DI-02 is the sum of the core power plus the analog power plus the power dissipated in the load(s). The following is the power dissipation for $V_{po} = 3.3V + 5\% = 3.465V$, which gives worst case results.

- Power (core)_{MAX} = $V_{DD_MAX} * (I_{DD_MAX} + I_{DDA_MAX}) = 3.465V * (80mA + 15mA) = 329.175mW$
- Power (outputs)_{MAX} = $V_{DDO_MAX} * I_{DDO_MAX} = 3.465V * 75mA = 259.87mW$
- Total Power = 329.2mW + 259.9mW = 589.1mW

2. Junction Temperature.

Junction temperature, Tj, is the temperature at the junction of the bond wire and bond pad and directly affects the reliability of the device. The maximum recommended junction temperature is 125°C.

The equation for Tj is as follows: $Tj = \theta_{JA} * Pd_{total} + T_A$

Tj = Junction Temperature

 θ_{JA} = Junction-to-Ambient Thermal Resistance

Pd_total = Total Device Power Dissipation (example calculation is in section 1 above)

T_A = Ambient Temperature

In order to calculate junction temperature, the appropriate junction-to-ambient thermal resistance θ_{JA} must be used. Assuming a moderate air flow of 200 linear feet per minute and a multi-layer board, the appropriate value is 66.6°C/W per Table 6 below. Therefore, Tj for an ambient temperature of 85°C with all outputs switching is:

 $85^{\circ}C + 0.589W * 66.6^{\circ}C/W = 124.2^{\circ}C$. This is below the limit of $125^{\circ}C$.

This calculation is only an example. Tj will obviously vary depending on the number of loaded outputs, supply voltage, air flow, and the type of board (single layer or multi-layer).

TABLE 6. THERMAL RESISTANCE θ_{JA} for 20-Lead TSSOP, Forced Convection

	_		
	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W

RELIABILITY INFORMATION

Table 6. $\boldsymbol{\theta}_{_{JA}} \text{vs.}$ Air Flow Table for 20 Lead TSSOP

	0	200	500
Single-Layer PCB, JEDEC Standard Test Boards	114.5°C/W	98.0°C/W	88.0°C/W
Multi-Layer PCB, JEDEC Standard Test Boards	73.2°C/W	66.6°C/W	63.5°C/W

TRANSISTOR COUNT The transistor count for 874003DI-02 is: 1408

PACKAGE OUTLINE - G SUFFIX FOR 20 LEAD TSSOP

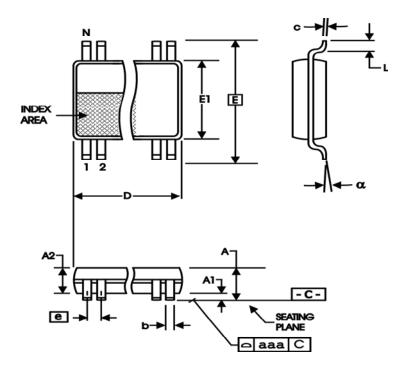


TABLE 7. PACKAGE DIMENSIONS

Millimeters		
MIN	МАХ	
2	20	
	1.20	
0.05	0.15	
0.80	1.05	
0.19	0.30	
0.09	0.20	
6.40	6.60	
6.40 BASIC		
4.30	4.50	
0.65	BASIC	
0.45	0.75	
0°	8°	
	0.10	
	MIN 2 0.05 0.80 0.19 0.09 6.40 4.30 0.65 0.45	

Reference Document: JEDEC Publication 95, MO-153

TABLE 8. ORDERING INFORMATION

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
874003DGI-02LF	ICS4003DI02L	20 Lead "Lead-Free" TSSOP	tube	-40°C to 85°C
874003DGI-02LFT	ICS4003DI02L	20 Lead "Lead-Free" TSSOP	tape & reel	-40°C to 85°C

NOTE: Parts that are ordered with an "LF" suffix to the part number are the Pb-Free configuration and are RoHS complaint.

REVISION HISTORY

Rev	Table	Page	Description of Change	Date
A	Funtion T	1 1 8	Corrected typo 'QA0, nQA0:QA1, nQA1'. Removed HiPerClockS logo. Removed HiPerClockS references from drawings.	5/1/13
A	Т8	-	Ordering Information - removed leaded devices. Updated data sheet format.	7/17/15
А			Product Discontinuation Notice - Last time buy expires September 7, 2016. PDN N-16-02.	3/11/16



Corporate Headquarters 6024 Silver Creek Valley Road San Jose, California 95138

Sales 800-345-7015 or +408-284-8200 Fax: 408-284-2775 www.IDT.com

Technical Support email: clocks@idt.com

DISCLAIMER Integrated Device Technology, Inc. (IDT) and its subsidiaries reserve the right to modify the products and/or specifications described herein at any time and at IDT's sole discretion. All information in this document, including descriptions of product features and performance, is subject to change without notice. Performance specifications and the operating parameters of the described products are determined in the independent state and are not guaranteed to perform the same way when installed in customer products. The information contained herein is provided without representation or warranty of any kind, whether express or implied, including, but not limited to, the suitability of IDT's products for any particular purpose, an implied warranty of merchantability, or non-infringement of the intellectual property rights of others. This document is presented only as a guide and does not convey any license under intellectual property rights of IDT or any third parties.

IDT's products are not intended for use in applications involving extreme environmental conditions or in life support systems or similar devices where the failure or malfunction of an IDT product can be reasonably expected to significantly affect the health or safety of users. Anyone using an IDT product in such a manner does so at their own risk, absent an express, written agreement by IDT.

Integrated Device Technology, IDT and the IDT logo are registered trademarks of IDT. Other trademarks and service marks used herein, including protected names, logos and designs, are the property of IDT or their respective third party owners.